

Description

The HSBSS84LT1G uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

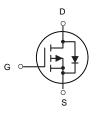
General Features

 $V_{DS} = -50V, I_D = -0.13A$ $R_{DS(ON)} < 5 \Omega @ V_{GS} = -10V$ $R_{DS(ON)} < 6 \Omega @ V_{GS} = -4.5V$

Application

Power switching application Hard switched and high frequency circuits DC-DC converter





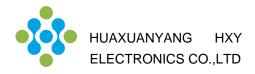
P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HSBSS84LT1G	SOT-23	B84/PD	3000

Absolute Maximum Ratings (T_A=25 $^{\circ}$ Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-50	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	Ι _D	-0.13	А
Pulsed Drain Current	I _{DM}	-0.5	А
Maximum Power Dissipation	PD	0.35	W
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C
Thermal Resistance ,Junction-to-Ambient ^(Note 2)	R _{0JA}	62.5	°C/W

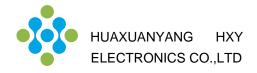


Electrical Characteristics (Ta=25[°]C unless otherwise specified)

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit	
Static							
V _{(BR)DSS}	Drain-source breakdown voltage	V _{GS} =0, I _D =250µA	-50			V	
V _{GS(th)}	Gate threshold voltage	$V_{DS}=V_{GS}$, $I_D=-250\mu A$	-0.8		-2.0	V	
I _{GSS}	Gate-body leakage current	$V_{DS}=0, V_{GS}=\pm 10V$, V _{GS} =±10V		±10	μA	
I _{DSS}	Zero gate voltage drain current	V _{DS} =-50V, V _{GS} =0V			-10	μA	
		V _{DS} =-40V, V _{GS} =0V			-100	nA	
R _{DS(on)}	Drain-source on-resistance ^a	V _{GS} =-10V, I _D =-0.13A		2	5	Ω	
		V _{GS} =-4.5V, I _D =-0.13A		2.5	6	Ω	
g fs	Forward transconductance ^a	V _{DS} =-25V, I _D =-0.13A	50			mS	
V_{SD}	Diode forward voltage	I _S =-0.13A,V _{GS} =0V			-1.0	V	
Dynamic							
Ciss	Input capacitance			25		pF	
Coss	Output capacitance	V _{DS} =-25V, V _{GS} =0V, f=1MHz		15			
Crss	Reverse transfer capacitance ^b			3.5			
Switching	b						
t _{d(on)}	Turn-on delay time			16.7			
tr	Rise time	V _{GS} =-10V,V _{DS} =-15V		8.6		nS	
t _{d(off)}	Turn-off delay time	I _D =-200mA, R _{GEN} =25Ω		17.9		113	
t _f	Fall time			5.3			

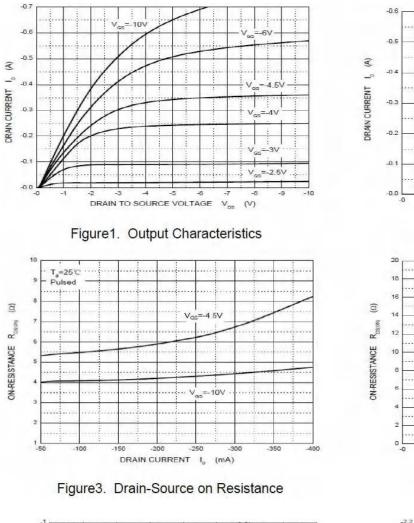
Notes :

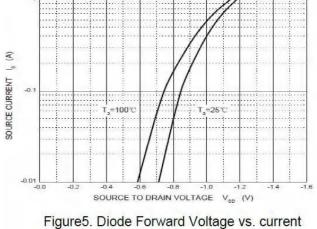
a. Pulse Test : Pulse width≤300µs, duty cycle ≤2%.b. Guaranteed by design, not subject to producting.



HSBSS84LT1G P-Channel Enhancement Mode MOSFET







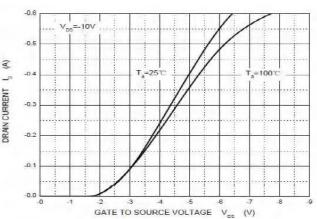


Figure2. Transfer Characteristics

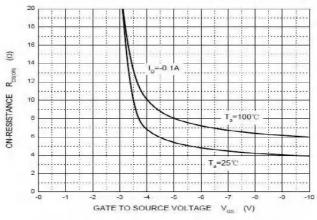


Figure4. Drain-Source on Resistance

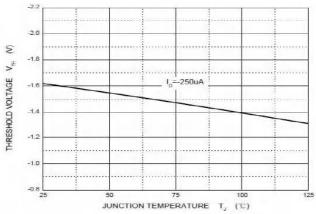
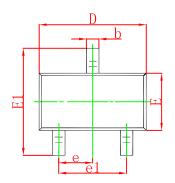
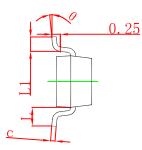


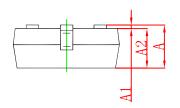
Figure6. Gate Threshold vs. Junction Temperature



SOT-23 Package Outline Dimensions

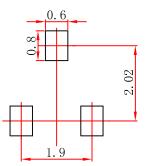






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
e	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

SOT-23 Suggested Pad Layout



Note:

1.Controlling dimension: in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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